Vishay Semiconductors

Hyperfast Rectifier, 60 A FRED Pt[®] G5



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PRIMARY CHARACTERISTICS									
I _{F(AV)}	60 A								
V _R	600 V								
V _F at I _F at 125 °C	1.7 V								
t _{rr} (typ.)	24								
I _{FSM}	450								
T _J max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

LINKS TO ADDITIONAL RESOURCES



FEATURES

- Hyperfast and optimized Q_{rr}
- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified meets JESD 201 class tin whisker 2 test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		600	V						
Average rectified forward current	I _{F(AV)}	T _C = 92 °C, D = 0.50	60							
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	450	А						
Repetitive peak forward current	I _{FRM}	T _C = 92 °C, D = 0.50, f = 20 kHz	120							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA		-	-					
Forward voltage	VF	I _F = 60 A	-	2.1	2.6	V				
Torward voltage	۷F	I _F = 60 A, T _J = 125 °C	-	1.7	-					
Reverse leakage current	I	$V_{R} = V_{R}$ rated	-	-	25					
neverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μΑ				
Junction capacitance	CT	V _R = 200 V	-	65	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)											
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100$) Α/μs, V _R = 30 V	-	24	-					
Reverse recovery time	t _{rr}	T _J = 25 °C		-	40	-	ns				
		T _J = 125 °C		-	52	-					
Peak recovery current	1	T _J = 25 °C	I _F = 40 A dI _F /dt = 1000 A/µs	-	12.5	-	A				
Feak recovery current	I _{RRM}	T _J = 125 °C	$dI_{F}/dt = 1000 \text{ A/}\mu\text{s}$ $V_{B} = 400 \text{ V}$	-	27	-					
Davience was a view of a view	0	T _J = 25 °C		-	235	-	nC				
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	900	-					
	+	T _J = 25 °C		-	42	-	ns				
Reverse recovery time	t _{rr}	T _J = 125 °C		-	54	-					
Deals receiver a surrent		T _J = 25 °C	$I_{\rm F} = 60 {\rm A}$	-	14	-	A				
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs V _B = 400 V	-	29	-					
	0	T _J = 25 °C] ``	-	280	-	nC				
Reverse recovery charge	Q _{rr}	T _J = 125 °C]	-	1025	-					

THERMAL - MECHANICAL SPECIFICATIONS											
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS					
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.63	°C/W					
Weight			-	5.5	-	g					
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)					
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C					
Marking device		Case style: TO-247AD 2L		E5PW6	5006LH						

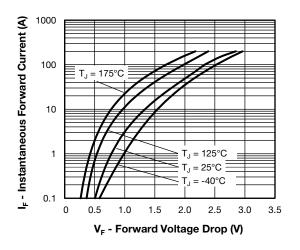


Fig. 1 - Forward Voltage Drop Characteristics

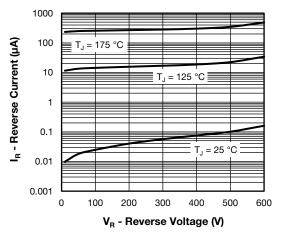


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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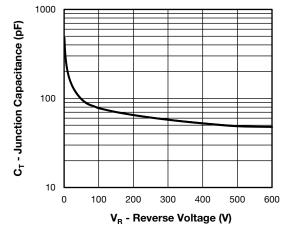


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

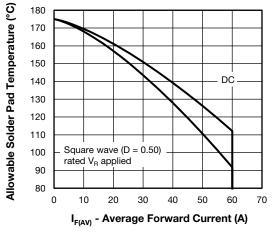


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

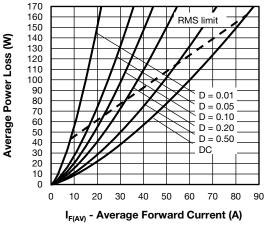


Fig. 5 - Forward Power Loss Characteristics

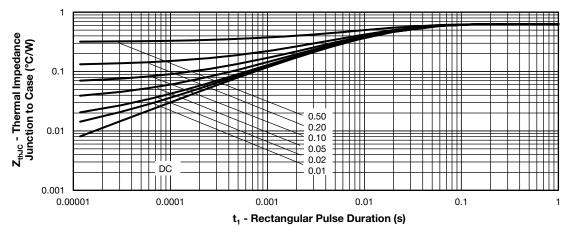


Fig. 6 - Transient Thermal Impedance, Junction to Case

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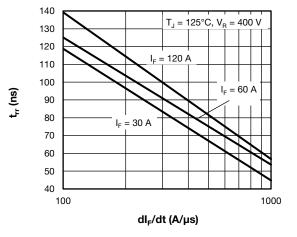


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

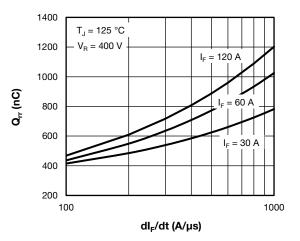


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

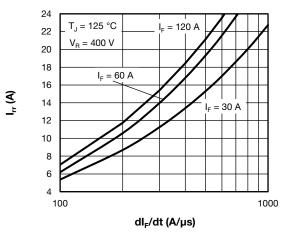


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

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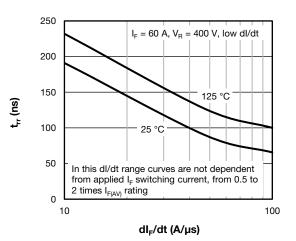
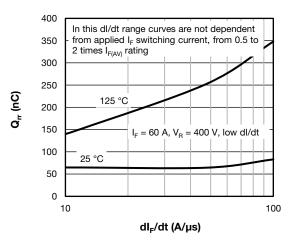


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt





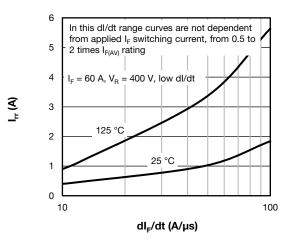


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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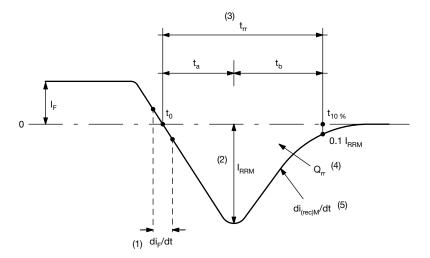


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- ⁽¹⁾ di_F/dt rate of change of current through zero crossing ⁽²⁾ I_{RRM} peak reverse recovery current ⁽³⁾ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM} ⁽⁴⁾ Q_{rr} area under curve defined by t₀ and t_{10 %}

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

⁽⁵⁾ $di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	Е	5	Р	w	60	06	L	Н	N3	
	1	2	3	4	5	6	7	8	9	10	
	- Vishay Semiconductors product										
	2 - Circuit configuration E = single diode										
	3 - FRED Pt [®] Gen 5										
	4 -	- P=	TO-247	' packag	je						
	5 - Process type: X = warp hyperfast recovery										
	6 -	Cur	rent rati	ng 60 =	60 A)						
	7 -	Volt	age rati	ng (06 =	= 600 V)						
	8 -	8 - Package: L = long lead (TO-247AD)									
	9 -	9 - H = AEC-Q101 qualified									
	10 -			ntal digit en-free,		complia	nt, and	totally l	ead (Pb)-free	

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5PW6006LHN3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS		
Dimensions	www	v.vishay.com/doc?95536
Part marking information	www	r.vishay.com/doc?95648
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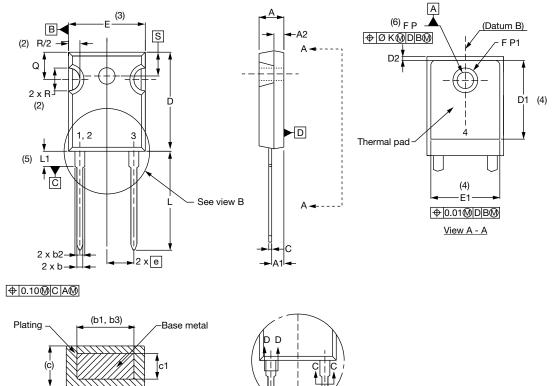
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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b, b2)

(4)

View	<u>/ B</u>

SYMBOL	MILLIMETERS INCHES		NOTES SYMBOL	MILLIMETERS		INCHES		NOTES			
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES	STMDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102		E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098		е	5.46	BSC	0.215	BSC	
b	0.99	1.40	0.039	0.055		ØК	0.2	254	0.0)10	
b1	0.99	1.35	0.039	0.053		L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092		ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053					•		•

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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